

## N-Channel Power MOSFET

600V, 18A, 0.19Ω

### FEATURES

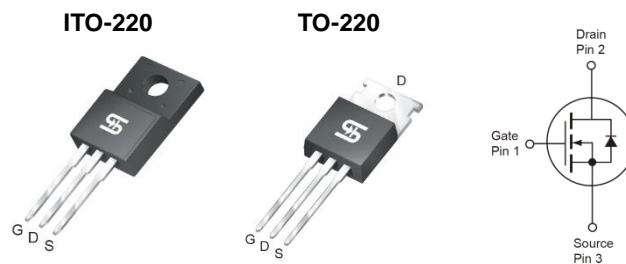
- Super-Junction technology
- High performance, small  $R_{DS(on)} * Q_g$  figure of merit (FOM)
- High ruggedness performance
- 100% UIS tested
- High commutation performance
- Pb-free plating
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

### KEY PERFORMANCE PARAMETERS

| PARAMETER          | VALUE | UNIT |
|--------------------|-------|------|
| $V_{DS}$           | 600   | V    |
| $R_{DS(on)}$ (max) | 0.19  | Ω    |
| $Q_g$              | 31    | nC   |

### APPLICATIONS

- Power Supply
- AC/DC LED Lighting



### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

| PARAMETER   | SYMBOL         | ITO-220                   | TO-220 | UNIT |
|---|----------------|---------------------------|--------|------|
| Drain-Source Voltage                                | $V_{DS}$       | 600                       |        | V    |
| Gate-Source Voltage                                 | $V_{GS}$       | ±30                       |        | V    |
| Continuous Drain Current <sup>(Note 1)</sup>        | $I_D$          | $T_C = 25^\circ\text{C}$  |        | A    |
|   |                | $T_C = 100^\circ\text{C}$ |        | A    |
| Pulsed Drain Current <sup>(Note 2)</sup>            | $I_{DM}$       | 54                        |        | A    |
| Total Power Dissipation @ $T_C = 25^\circ\text{C}$  | $P_{DTOT}$     | 33.8                      | 150.6  | W    |
| Single Pulsed Avalanche Energy <sup>(Note 3)</sup>  | $E_{AS}$       | 212.9                     |        | mJ   |
| Single Pulsed Avalanche Current <sup>(Note 3)</sup> | $I_{AS}$       | 2.6                       |        | A    |
| Operating Junction and Storage Temperature Range    | $T_J, T_{STG}$ | - 55 to +150              |        | °C   |

### THERMAL PERFORMANCE

| PARAMETER                              | SYMBOL          | ITO-220 | TO-220 | UNIT |
|--|-----------------|---------|--------|------|
| Junction to Case Thermal Resistance    | $R_{\theta JC}$ | 3.7     | 0.83   | °C/W |
| Junction to Ambient Thermal Resistance | $R_{\theta JA}$ | 62      |        | °C/W |

**Notes:**  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistances. The case thermal reference is defined at the solder mounting surface of the drain pins.  $R_{\theta JA}$  is guaranteed by design while  $R_{\theta CA}$  is determined by the user's board design.  $R_{\theta JA}$  shown below for single device operation on FR-4 PCB with minimum recommended footprint in still air.

| <b>ELECTRICAL SPECIFICATIONS</b> ( $T_A = 25^\circ\text{C}$ unless otherwise noted) |  |                                     |          |       |           |               |
|---|--|-------------------------------------|----------|-------|-----------|---------------|
| PARAMETER   | CONDITIONS   | SYMBOL                              | MIN      | TYP   | MAX       | UNIT          |
| <b>Static</b>   |  |                                     |          |       |           |               |
| Drain-Source Breakdown Voltage  | $V_{GS} = 0\text{V}, I_D = 250\mu\text{A}$   | $BV_{DSS}$                          | 600      | --    | --        | V             |
| Gate Threshold Voltage  | $V_{DS} = V_{GS}, I_D = 250\mu\text{A}$  | $V_{GS(TH)}$                        | 2.0      | 3.0   | 4.0       | V             |
| Gate Body Leakage   | $V_{GS} = \pm 30\text{V}, V_{DS} = 0\text{V}$  | $I_{GSS}$                           | --       | --    | $\pm 100$ | nA            |
| Zero Gate Voltage Drain Current   | $V_{DS} = 600\text{V}, V_{GS} = 0\text{V}$   | $I_{DSS}$                           | --       | --    | 1         | $\mu\text{A}$ |
| Drain-Source On-State Resistance<br>(Note 4)  | $V_{GS} = 10\text{V}, I_D = 6\text{A}$   | $R_{DS(on)}$                        | --       | 0.17  | 0.19      | $\Omega$      |
| <b>Dynamic</b> (Note 5)   |  |                                     |          |       |           |               |
| Total Gate Charge   | $V_{DS} = 380\text{V}, I_D = 18\text{A},$<br>$V_{GS} = 10\text{V}$                           | $Q_g$                               | --       | 31    | --        | nC            |
| Gate-Source Charge  |  | $Q_{gs}$                            | --       | 8     | --        |               |
| Gate-Drain Charge   |  | $Q_{gd}$                            | --       | 12.6  | --        |               |
| Input Capacitance   | $V_{DS} = 100\text{V}, V_{GS} = 0\text{V},$<br>$f = 1.0\text{MHz}$                           | $C_{iss}$                           | --       | 1273  | --        | pF            |
| Output Capacitance  |  | $C_{oss}$                           | --       | 92    | --        |               |
| Gate Resistance   | $F = 1\text{MHz}, \text{open drain}$   | $R_g$                               | --       | 3.1   | --        | $\Omega$      |
| <b>Switching</b> (Note 6)   |  |                                     |          |       |           |               |
| Turn-On Delay Time  | $V_{DD} = 380\text{V},$<br>$R_{GEN} = 25\Omega,$<br>$I_D = 18\text{A}, V_{GS} = 10\text{V},$ | $t_{d(on)}$                         | --       | 36    | --        | ns            |
| Turn-On Rise Time   |  | $t_r$                               | --       | 21    | --        |               |
| Turn-Off Delay Time   |  | $t_{d(off)}$                        | --       | 95    | --        |               |
| Turn-Off Fall Time  |  | $t_f$                               | --       | 21    | --        |               |
| <b>Source-Drain Diode</b>   |  |                                     |          |       |           |               |
| Forward On Voltage (Note 4)   | $I_S = 18\text{A}, V_{GS} = 0\text{V}$   | $V_{SD}$                            | --       | --    | 1.4       | V             |
| Reverse Recovery Time   | $V_R = 100\text{V}, I_S = 18\text{A}$  | $t_{rr}$                            | --       | 359.4 | --        | ns            |
| Reverse Recovery Charge   |  | $di_f/dt = 100\text{A}/\mu\text{s}$ | $Q_{rr}$ | --    | 4.54      | --            |

**Notes:**

1. Current limited by package.
2. Pulse width limited by the maximum junction temperature.
3.  $L = 63\text{mH}, I_{AS} = 2.6\text{A}, V_{DD} = 50\text{V}, R_G = 25\Omega,$  Starting  $T_J = 25^\circ\text{C}$
4. Pulse test:  $PW \leq 300\mu\text{s},$  duty cycle  $\leq 2\%$ .
5. For DESIGN AID ONLY, not subject to production testing.
6. Switching time is essentially independent of operating temperature.

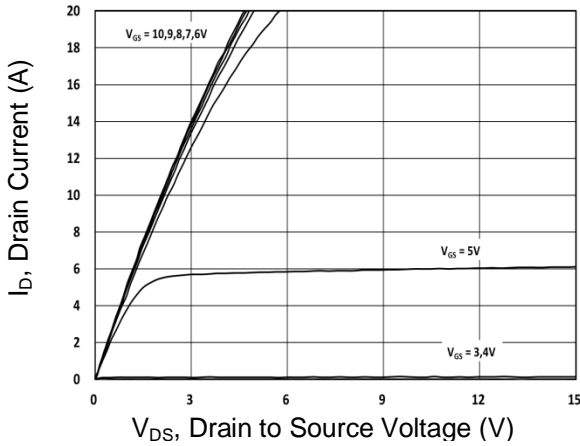
**ORDERING INFORMATION**

| PART NO.         | PACKAGE | PACKING      |
|------------------|---------|--------------|
| TSM60NB190CI C0G | ITO-220 | 50pcs / Tube |
| TSM60NB190CZ C0G | TO-220  | 50pcs / Tube |

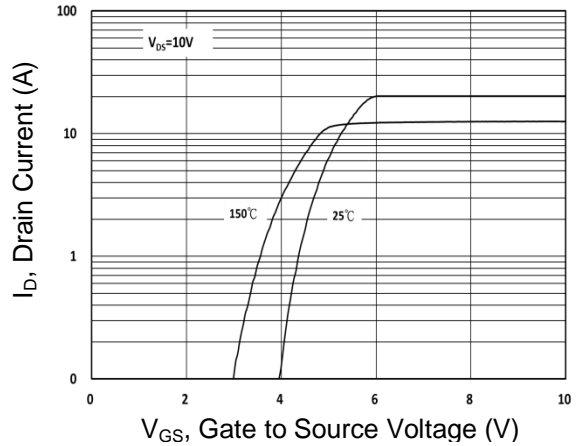
**CHARACTERISTICS CURVES**

( $T_C = 25^\circ\text{C}$  unless otherwise noted)

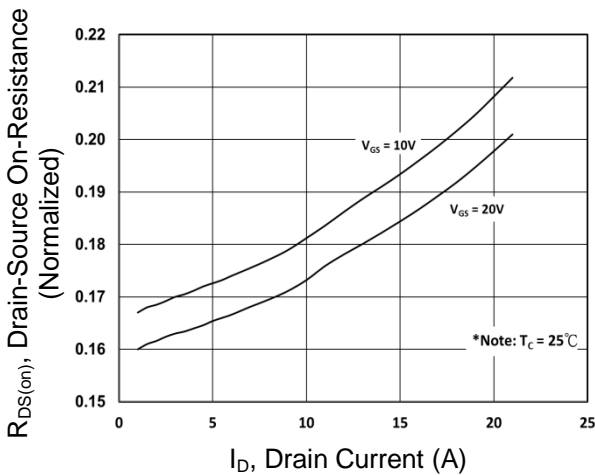
**Output Characteristics**



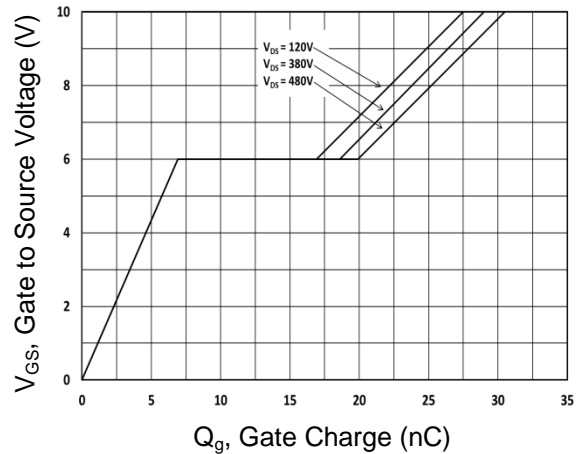
**Transfer Characteristics**



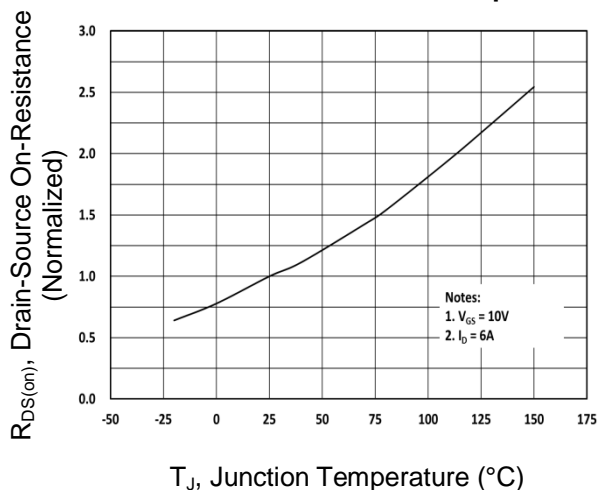
**On-Resistance vs. Drain Current**



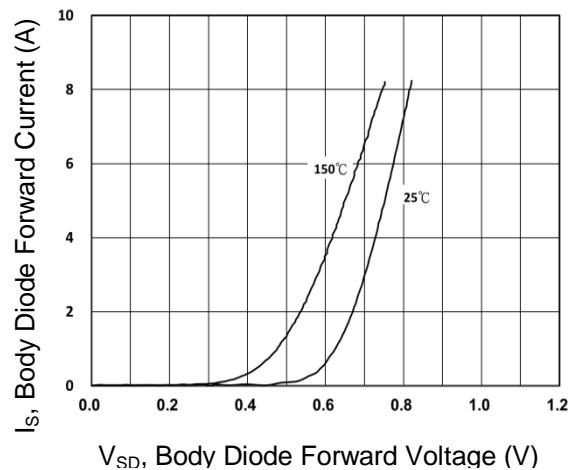
**Gate-Source Voltage vs. Gate Charge**



**On-Resistance vs. Junction Temperature**



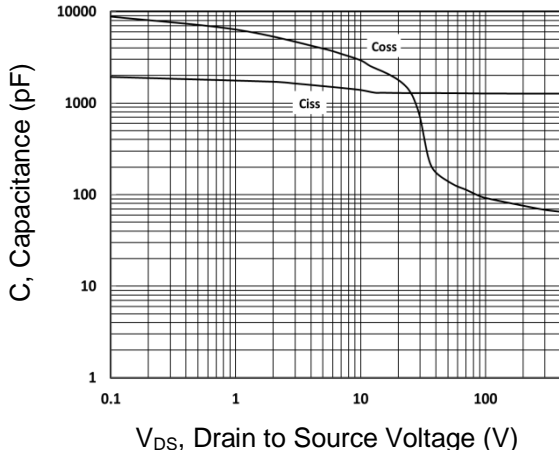
**Source-Drain Diode Forward Current vs. Voltage**



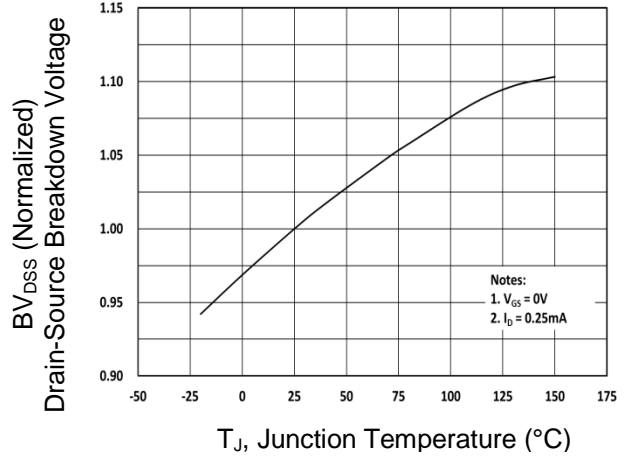
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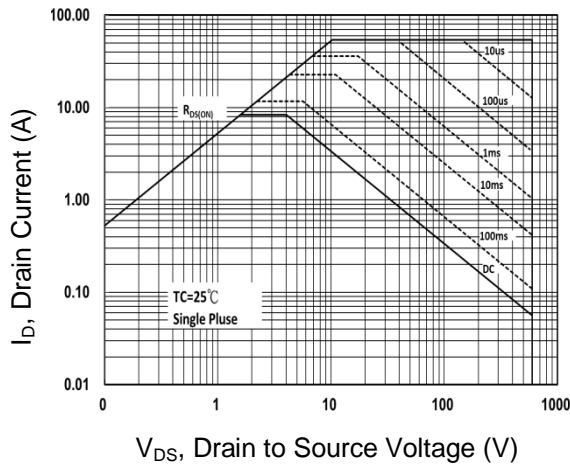
**Capacitance vs. Drain-Source Voltage**



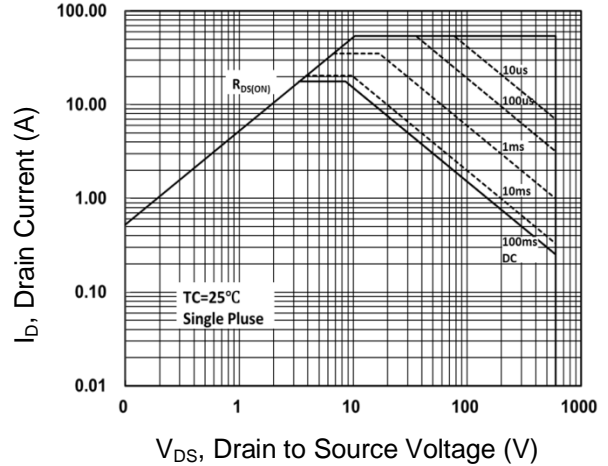
**$BV_{DSS}$  vs. Junction Temperature**



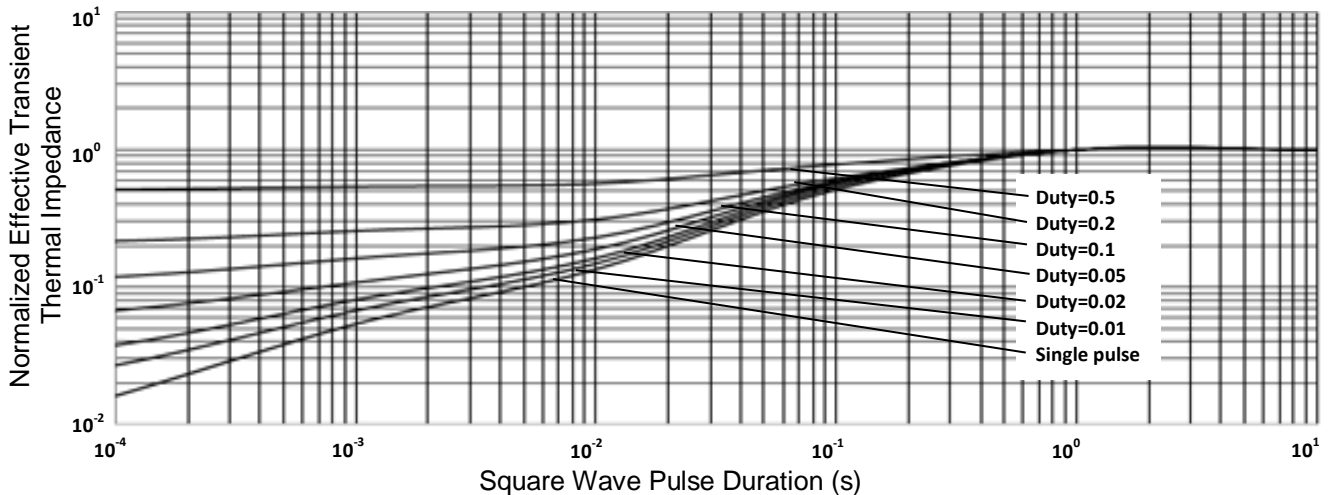
**Maximum Safe Operating Area (ITO-220)**



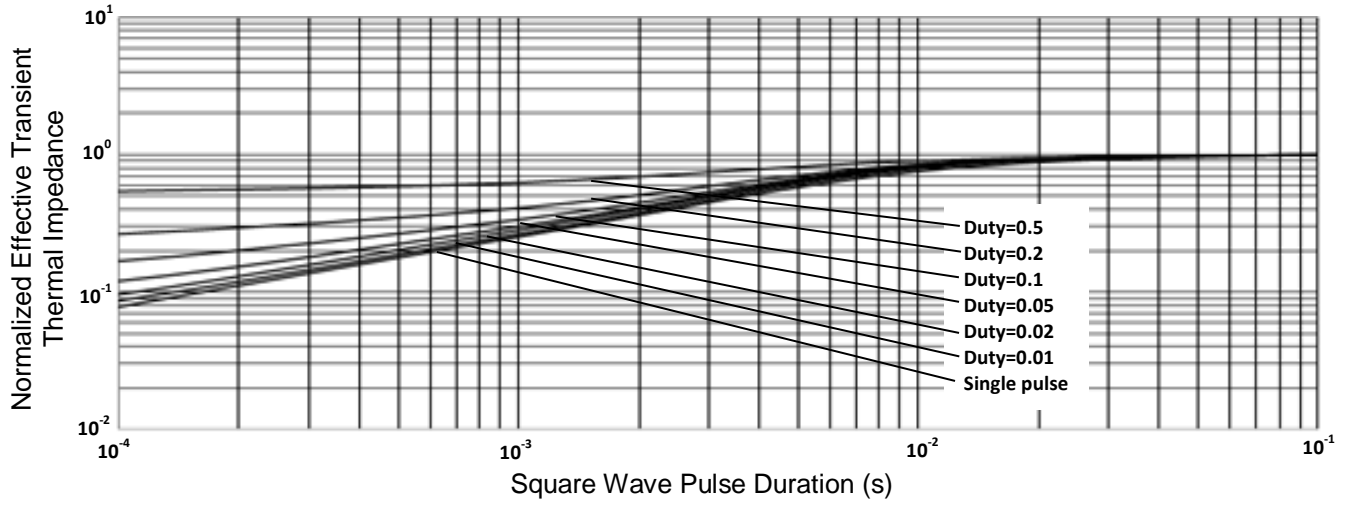
**Maximum Safe Operating Area (TO-220)**



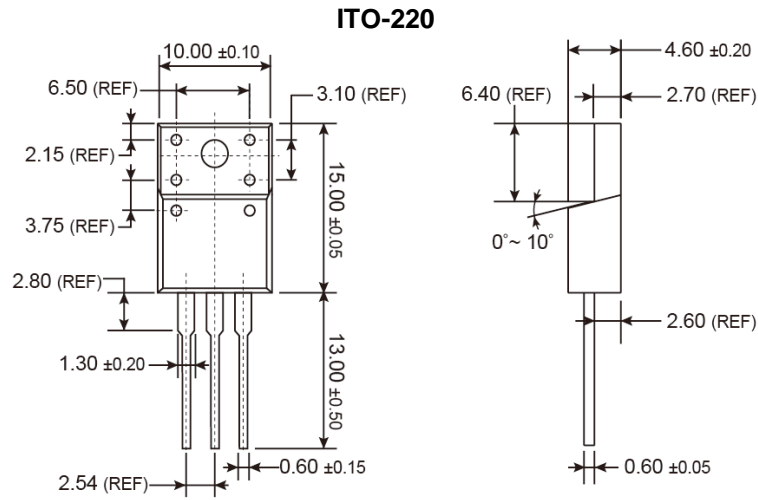
**Normalized Thermal Transient Impedance, Junction-to-Case (ITO-220)**



**Normalized Thermal Transient Impedance, Junction-to-Case (TO-220)**



**PACKAGE OUTLINE DIMENSIONS** (Unit: Millimeters)

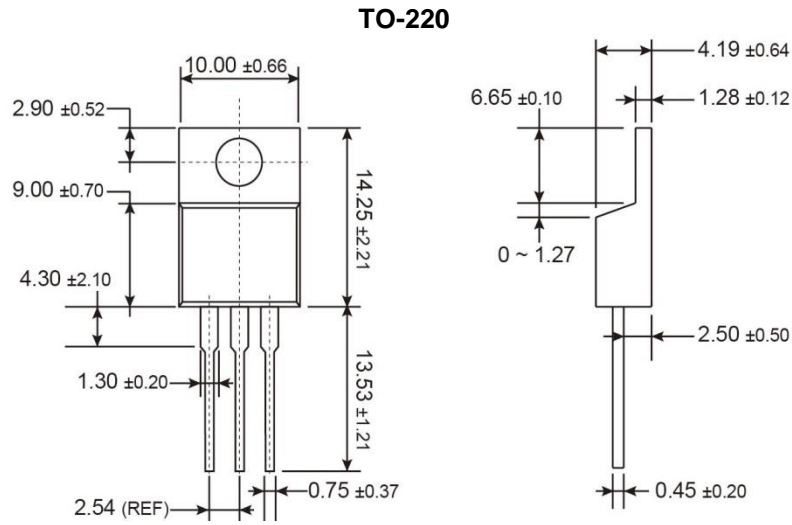


**MARKING DIAGRAM**

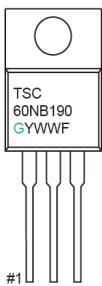


- G** = Halogen Free
- Y** = Year Code
- WW** = Week Code (01~52)
- F** = Factory Code

**PACKAGE OUTLINE DIMENSIONS** (Unit: Millimeters)



**MARKING DIAGRAM**



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